

VOLENTINE FRANCOS & WHITT, P.L.L.C.
One Freedom Square
11951 Freedom Drive, Suite 1260
Reston, VA 20190 U.S.A.
Tel: 1.703.715.0870
Fax: 1.703.715.0877
Email: iplaw@volentine.com

**FACSIMILE
TRANSMITTAL**

Date: February 2, 2005

**RECEIVED
CENTRAL FAX CENTER**

To: Examiner Lindsay, Jr.
U.S. Patent and Trademark Office

FEB 02 2005

Fax No: 703-872-9306

Ph. No:

From: Andrew J. Telesz, Jr.

Subject: Serial No.: 10/762,361
Our Ref. No.: OKI.206D3

No. of Pages (including cover): 9

Comments:

PLEASE CALL IF YOU EXPERIENCE ANY DIFFICULTIES RECEIVING ALL PAGES

PLEASE NOTE that this message is intended for the use of the individual or entity to which it is addressed and may contain information that is privileged, confidential and exempt from disclosure under applicable law. If the reader of the message is not the intended recipient, or the employee or agent responsible for delivering the message to the intended recipient, you are hereby notified that any dissemination, distribution or copying of this communication is strictly prohibited. If you have received this communication in error, please notify us immediately by telephone, and either return the message and any attachments to us at the above address via regular postal service, or destroy the message and any attachments.

CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)Applicant(s): **Masahiro Yoshida et al.**Docket No.
OKI.206D3Application No.
10/762,361Filing Date
January 23, 2004Examiner
W. Lindsay, Jr.Group Art Unit
2812Invention: **METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE INCLUDING A MOSFET WITH NITRIDE SIDEWALLS**

I hereby certify that this Letter Resubmitting Earlier Filed Information Disclosure Statement
(Identify type of correspondence)
is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. 703-872-9306)
on February 2, 2005
(Date)

Andrew J. Telesz, Jr.

(Typed or Printed Name of Person Signing Certificate)

(Signature)

Note: Each paper must have its own certificate of mailing.

Via Facsimile 703-872-9306**OKI.206D3****IN THE UNITED STATES PATENT AND TRADEMARK OFFICE****In re PATENT APPLICATION of****RECEIVED
CENTRAL FAX CENTER**

Masahiro Yoshida et al.

Group Art Unit: 2812

FEB 02 2005

Serial No.: 10/762,361

Examiner: W. Lindsay, Jr.

Filed: January 23, 2004

Conf. No.: 4915

FOR: METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE INCLUDING
A MOSFET WITH NITRIDE SIDEWALLS**LETTER RESUBMITTING EARLIER FILED INFORMATION DISCLOSURE
STATEMENT**

U.S. Patent and Trademark Office
Customer Window, Mail Stop Issue Fee
Randolph Building
401 Dulany Street
Alexandria, VA 22314

Date: February 2, 2005

Sir:

The Notice of Allowability dated January 21, 2005, does not acknowledge receipt of the Information Disclosure Statement filed on December 23, 2004.

Accordingly, enclosed is a copy of the Information Disclosure Statement and Form PTO/SB/08A form filed on December 23, 2004. Also enclosed is a copy of a dated, stamped postcard receipt provided as evidence that the above noted Information Disclosure Statement was received by the U.S. Patent Office on December 23, 2004.

Applicants respectfully request the Examiner to acknowledge that the Information Disclosure Statement has been received, and to confirm that the documents will be cited of record.

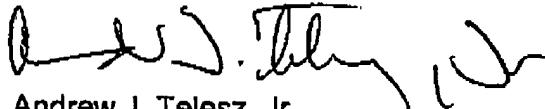
Serial No.: 10/762,361

In the event that there are any outstanding matters remaining in the present application, please contact Andrew J. Telesz, Jr. (Reg. No. 33,581) at (703) 715-0870 in the Washington, D.C. area, to discuss these matters.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment for any additional fees that may be required, or credit any overpayment, to Deposit Account No. 50-0238.

Respectfully submitted,

VOLENTINE FRANCOS & WHITT, P.L.L.C.



Andrew J. Telesz, Jr.
Registration No. 33,581

One Freedom Square
11951 Freedom Drive, Suite 1260
Reston, Virginia 20190
Telephone No.: (703) 715-0870
Facsimile No.: (703) 715-0877

Enclosures: • Copy of Information Disclosure Statement and PTO/SB/08A form filed on December 23, 2004
• Copy of dated, stamped postcard receipt

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT
(Under 37 CFR 1.97(b) or 1.97(c))

Docket No.
OKI.206D3

In Re Application Of: Masahiro Yoshida et al.

Application No.	Filing Date	Examiner	Customer No.	Group Art Unit	Confirmation No.
10/762,361	January 23, 2004	W. Lindsay, Jr.		2812	4915

Title: **METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE INCLUDING A MOSFET
WITH NITRIDE SIDEWALLS**

Address to:
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

37 CFR 1.97(b)

1. The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an International application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.

37 CFR 1.97(c)

2. The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:
 - the statement specified in 37 CFR 1.97(e);
 - OR**
 - the fee set forth in 37 CFR 1.17(p).

U.S. Patent No. 4,810,666 is provided as an English language equivalent of
JP 61-16571.

**TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT
(Under 37 CFR 1.97(b) or 1.97(c))**
**Docket No.
OKI.206D3**
In Re Application: Masahiro Yoshida et al.

Application No.	Filing Date	Examiner	Customer No.	Group Art Unit	Confirmation No.
10/762,361	January 23, 2004	W. Lindsay, Jr.		2812	4915

Title: METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE INCLUDING A MOSFET
WITH NITRIDE SIDEWALLS

Payment of Fee

(Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p))

A check in the amount of _____ is attached.

The Director is hereby authorized to charge and credit Deposit Account No. 50-0238 as described below.

- Charge the amount of _____
- Credit any overpayment.
- Charge any additional fee required.

Payment by credit card. Form PTO-2038 is attached.

WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.
Certificate of Transmission by Facsimile*

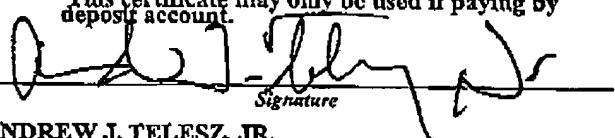
I certify that this document and authorization to charge deposit account is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. _____)

(Date)

Signature

Typed or Printed Name of Person Signing Certificate

*This certificate may only be used if paying by deposit account.


Certificate of Mailing by First Class Mail

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to "Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450" [37 CFR 1.8(a)] on _____

(Date)

Signature of Person Mailing Correspondence

Typed or Printed Name of Person Mailing Certificate

ANDREW J. TELESZ, JR.

REG. NO. 33,581

Dated: December 23, 2004

VOLENTINE FRANCOS & WHITT, P.L.L.C.
ONE FREEDOM SQUARE
11951 FREEDOM DRIVE, SUITE 1260
RESTON, VA 20190
TEL. NO. (703) 715-0870

CC:

**STATEMENT UNDER 37 CFR 1.97(e) ACCOMPANYING
INFORMATION DISCLOSURE STATEMENT**

Docket No.
OKI.206D3

In Re Application Of: Masahiro Yoshida et al.

Application No.	Filing Date	Examiner	Customer No.	Group Art Unit	Confirmation No.
10/762,361	January 23, 2004	W. Lindsay, Jr.		2812	4915

Invention: **METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE INCLUDING A MOSFET WITH NITRIDE SIDEWALLS**

COMMISSIONER FOR PATENTS:

This is a statement under the provisions of 37 CFR 1.97(e) in the above-identified application.

Check applicable statement herebelow:

Statement Under 37 CFR 1.97(e)(1)

Each item of information contained in the accompanying Information Disclosure Statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the Information Disclosure Statement.

Statement Under 37 CFR 1.97(e)(2)

No item of information contained in the accompanying Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the undersigned person, after making reasonable inquiry, no item of information contained in the accompanying Information Disclosure Statement was known to any individual designated in 37 CFR 1.56(c) more than three months prior to the filing of the Information Disclosure Statement.

Signature

Dated: December 23, 2004

ANDREW J. TELESZ, JR.
REG. NO. 33,581

VOLENTINE FRANCOS & WHITT, P.L.L.C.
ONE FREEDOM SQUARE
11951 FREEDOM DRIVE, SUITE 1260
RESTON, VA 20190
TEL. NO. (703) 715-0870

Certificate of Mailing by First Class Mail

I certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to "Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450" [37 CFR 1.8(a)] on _____.

(Date)

Signature of Person Mailing Correspondence

Typed or Printed Name of Person Mailing Correspondence

CC:

U.S. PATENT AND TRADEMARK OFFICE; U.S. DEPARTMENT OF COMMERCE
Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number.

Approved for use through 07/31/2006, OMB 0651-0031
U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE
to a collection of information unless it contains a valid OMB control number.

Substitute for Form 1449/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Shea

45

Complete it now!

Application Number	10/762,361
Filing Date	January 23, 2004
First Named Inventor	Masahiro Yoshida et
Art Unit	2812
Examiner Name	W. Lindsey, Jr.
Attorney Docket Number	OKI.206D3

U. S. PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No.*	Foreign Patent Document	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages Or Relevant Figures Appear
		Country Code* "Number" "Kind Code" (if known)	MM-DD-YYYY		
		JP 09-045908	02/14/1997		
		JP 05-198794	08/06/1993		
		JP 61-16571	01/24/1986		
		JP 09-008307	01/10/1997		
1		JP 09-129872	05/16/1997		

**Examiner
Signature**

Data Considered

EXAMINER: Initial if references considered, whether or not citation is in conformance with MPEP 608. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. *Applicant's unique citation designation number (optional). ² See Kinda Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assistance in completing the form, call 1-800-PTO-9199 (1-800-786-9199) and select option 2.

ATTY DOCKET #: OKI.206D3**APPLICANT:** Masahiro Yoshida et al. **DUE DATE:****SERIAL NO.:** 10/762,361 **FILING DATE:** January 23, 2004**TITLE:** METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE
INCLUDING A MOSFET WITH NITRIDE SIDEWALLS**RECEIPT OF THE FOLLOWING PAPERS IS ACKNOWLEDGED:**Transmittal of Information Disclosure Statement; Statement Under 37 C.F.R.
1.97(e); PTO/SB/08A Form; English translation of Japanese Office Action; and
Six (6) references.**DATE:** December 23, 2004 **PATENT & TRADEMARK OFFICE**[Check No. N/A]